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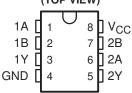
PERIPHERAL DRIVERS FOR HIGH-CURRENT SWITCHING AT VERY HIGH SPEEDS

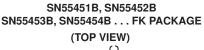
- Characterized for Use to 300 mA
- High-Voltage Outputs
- No Output Latch-Up at 20 V (After Conducting 300 mA)
- High-Speed Switching
- Circuit Flexibility for Varied Applications
- TTL-Compatible Diode-Clamped Inputs
- Standard Supply Voltages
- Plastic DIP (P) With Copper Lead Frame Provides Cooler Operation and Improved Reliability
- Package Options Include Plastic Small-Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

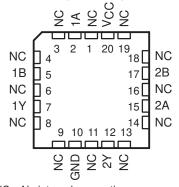
		-
DEVICE	LOGIC OF COMPLETE CIRCUIT	PACKAGES
SN55451B	AND	FK, JG
SN55452B	NAND	JG
SN55453B	OR	FK, JG
SN55454B	NOR	JG
SN75451B	AND	D, P
SN75452B	NAND	D, P
SN75453B	OR	D, P
SN75454B	NOR	D, P

SUMMARY OF DEVICES

SN55451B, SN55452B, SN55453B, SN55454B . . . JG PACKAGE SN75451B, SN75452B, SN75453B, SN75454B . . . D OR P PACKAGE (TOP VIEW)







NC - No internal connection

description

The SN55451B through SN55454B and SN75451B through SN75454B are dual peripheral drivers designed for use in systems that employ TTL logic. This family is functionally interchangeable with and replaces the SN75450 family and the SN75450A family devices manufactured previously. The speed of the devices is equal to that of the SN75450 family, and the parts are designed to ensure freedom from latch-up. Diode-clamped inputs simplify circuit design. Typical applications include high-speed logic buffers, power drivers, relay drivers, lamp drivers, MOS drivers, line drivers, and memory drivers.

The SN55451B/SN75451B, SN55452B/SN75452B, SN55453B/SN75453B, and SN55454B/SN75454B are dual peripheral AND, NAND, OR, and NOR drivers, respectively (assuming positive logic), with the output of the logic gates internally connected to the bases of the npn output transistors.

The SN55' drivers are characterized for operation over the full military range of -55° C to 125° C. The SN75' drivers are characterized for operation from 0° C to 70° C.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		SN55'	SN75'	UNIT	
Supply voltage, V _{CC} (see Note 1)		7	7	V	
Input voltage, VI		5.5	5.5	V	
Inter-emitter voltage (see Note 2)	5.5	5.5	V		
Off-state output voltage, V _O	30	30	V		
Continuous collector or output current, IOK (see Note 3)	400	400	mA		
Peak collector or output current, I _I (t _W \leq 10 ms, duty cycle \leq 50%, s	ee Note 4)	500	500	mA	
Continuous total power dissipation		See Diss	See Dissipation Rating		
Operating free-air temperature range, TA		-55 to 125	0 to 70	°C	
Storage temperature range, T _{Stg}		-65 to 150	-65 to 150	°C	
Case temperature for 60 seconds	FK package	260		°C	
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	JG package	300		°C	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D or P package		260	°C	

NOTES: 1. Voltage values are with respect to network GND, unless otherwise specified.

2. This is the voltage between two emitters of a multiple-emitter transistor.

3. This value applies when the base-emitter resistance (R_{BF}) is equal to or less than 500 Ω .

4. Both halves of these dual circuits may conduct rated current simultaneously; however, power dissipation averaged over a short time interval must fall within the continuous dissipation rating.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	—
FK	1375 mW	11.0 mW/°C	880 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	210 mW
Р	1000 mW	8.0 mW/°C	640 mW	—

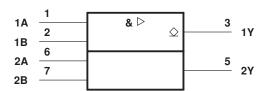
recommended operating conditions

		SN55'			SN75'		UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	4.5	5	5.5	4.75	5	5.25	V
High-level input voltage, VIH	2			2			V
Low-level input voltage, VIL			0.8			0.8	V
Operating free-air temperature, T _A	-55		125	0		70	°C



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logic symbol[†]

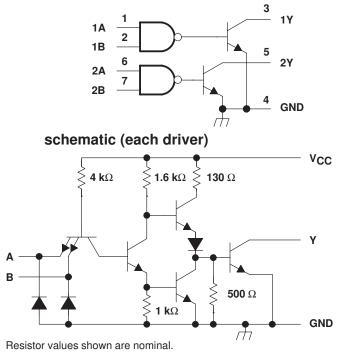


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

Pin numbers shown are for the D, JG, and P packages.

F	FUNCTION TABLE (each driver)									
Α	В	Y								
L	L	L (on state)								
L	Н	L (on state)								
н	L	L (on state)								
н	Н	H (off state)								
positive Y =	e logic: AB or									

logic diagram (positive logic)



electrical characteristics over recommended operating free-air temperature range

	DADAMETED	TEAT OON	DITIONOT	S	N55451E	3	S	N75451E	3	UNIT
	PARAMETER	TEST CON	DITIONS+	MIN	TYP§	MAX	MIN	TYP§	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	lj = -12 mA		-1.2	-1.5		-1.2	-1.5	V
Max		$V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$	V _{IL} = 0.8 V,		0.25	0.5		0.25	0.4	v
VOL	Low-level output voltage	$V_{CC} = MIN,$ $I_{OL} = 300 \text{ mA}$	V _{IL} = 0.8 V,		0.5	0.8		0.5	0.7	v
ЮН	High-level output current	$V_{CC} = MIN,$ $V_{OH} = 30 V$	V _{IH} = MIN,			300			100	μA
Ц	Input current at maximum input voltage	$V_{CC} = MAX,$	Vj = 5.5 V			1			1	mA
Ιн	High-level input current	V _{CC} = MAX,	V _I = 2.4 V			40			40	μA
Ι _{ΙL}	Low-level input current	V _{CC} = MAX,	$V_{ } = 0.4 V$		-1	-1.6		-1	-1.6	mA
ІССН	Supply current, outputs high	V _{CC} = MAX,	V _I = 5 V		7	11		7	11	mA
ICCL	Supply current, outputs low	V _{CC} = MAX,	$V_{I} = 0$		52	65		52	65	mA

[‡] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. § All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

	PARAMETER			TEST CONDITIONS			MAX	UNIT
^t PLH	Propagation delay time, low-to-high-level	output				18	25	
^t PHL	PHL Propagation delay time, high-to-low-level output		I _O ≈ 200 mA,	C _L = 15 pF,		18	25	20
^t TLH	t _{TLH} Transition time, low-to-high-level output		R _L = 50 Ω,	See Figure 1		5	8	ns
^t THL	Transition time, high-to-low-level output					7	12	
Val	High lovel output voltage after awitching	SN55451B	V _S = 20 V,	l _O ≈ 300 mA,		V _S -6.5		mV
VOH	High-level output voltage after switching	SN75451B	See Figure 2	-	V _S -6.5			IIIV



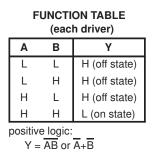
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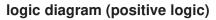
logic symbol[†]

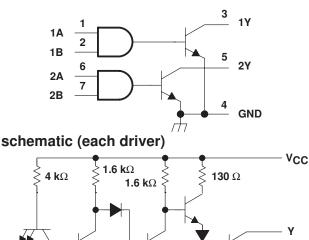


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

Pin numbers shown are for the D, JG, and P packages.







 $B \xrightarrow{1 \text{ k}\Omega} 1 \text{ k}\Omega \xrightarrow{500 \Omega} GND$

Resistor values shown are nominal.

electrical characteristics over recommended operating free-air temperature range

Α

	DADAMETED	TEOTOON		5	6N55452E	3	S	N75452E	3	UNIT
	PARAMETER	TEST CONDITIONS [‡]		MIN	ΤΥΡ§	MAX	MIN	TYP§	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	$I_{I} = -12 \text{ mA}$		-1.2	-1.5		-1.2	-1.5	V
		$V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$	$V_{IH} = MIN,$		0.25	0.5		0.25	0.4	v
VOL	VOL Low-level output voltage	$V_{CC} = MIN,$ $I_{OL} = 300 \text{ mA}$	$V_{IH} = MIN,$		0.5	0.8		0.5	0.7	v
ЮН	High-level output current	V _{CC} = MIN, V _{OH} = 30 V	V _{IL} = 0.8 V,			300			100	μA
Ιį	Input current at maximum input voltage	$V_{CC} = MAX,$	$V_{I} = 5.5 V$			1			1	mA
Чн	High-level input current	$V_{CC} = MAX,$	V _I = 2.4 V			40			40	μA
ЧL	Low-level input current	$V_{CC} = MAX,$	$V_I = 0.4 V$		-1.1	-1.6		-1.1	-1.6	mA
ІССН	Supply current, outputs high	V _{CC} = MAX,	V _I = 0		11	14		11	14	mA
ICCL	Supply current, outputs low	$V_{CC} = MAX,$	V _I = 5 V		56	71		56	71	mA

[‡] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. § All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

	PARAMETER			NDITIONS	MIN	ТҮР	MAX	UNIT
^t PLH	Propagation delay time, low-to-high-level output					26	35	
^t PHL	Propagation delay time, high-to-low-level output		I _O ≈ 200 mA,			24	35	
^t TLH	TLH Transition time, low-to-high-level output		$R_L = 50 \Omega$,	See Figure 1		5	8	ns
^t THL	Transition time, high-to-low-level output					7	12	
Val	High-level output voltage after switching	SN55452B	V _S = 20 V,	l _O ≈ 300 mA,		V _S -6.5		mV
VOH	High-level output voltage after switching	SN75452B	See Figure 2	-	V _S -6.5			IIIV



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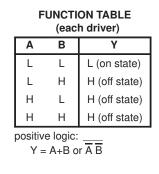
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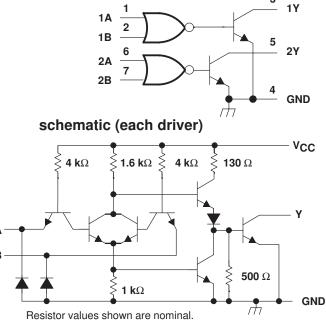
logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

Pin numbers shown are for the D, JG, and P packages.





logic diagram (positive logic)

electrical characteristics over recommended operating free-air temperature range

B

			DITIONOT	5	6N55453E	3	S	6N75453E	3	UNIT
	PARAMETER	TESTCON	TEST CONDITIONS [‡]		ΤΥΡ§	MAX	MIN	TYP§	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	l _l = –12 mA		-1.2	-1.5		-1.2	-1.5	V
Vei		$V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$	V _{IL} = 0.8 V,		0.25	0.5		0.25	0.4	V
VOL		$V_{CC} = MIN,$ $I_{OL} = 300 \text{ mA}$	V _{IL} = 0.8 V,		0.5	0.8		0.5	0.7	v
ЮН	High-level output current	V _{CC} = MIN, V _{OH} = 30 V	V _{IH} = MIN,			300			100	μA
Ιį	Input current at maximum input voltage	$V_{CC} = MAX,$	Vj = 5.5 V			1			1	mA
IIН	High-level input current	$V_{CC} = MAX,$	V _I = 2.4 V			40			40	μA
Ι _{ΙL}	Low-level input current	$V_{CC} = MAX,$	V _I = 0.4 V		-1	-1.6		-1	-1.6	mA
ІССН	Supply current, outputs high	$V_{CC} = MAX,$	V _I = 5 V		8	11		8	11	mA
ICCL	Supply current, outputs low	V _{CC} = MAX,	V _I = 0		54	68		54	68	mA

[‡] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. § All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, $V_{CC} = 5 V$, $T_A = 25^{\circ}C$

	PARAMETER		TEST CO	NDITIONS	MIN	ТҮР	MAX	UNIT
^t PLH	Propagation delay time, low-to-high-level	output				18	25	
^t PHL	tPHL Propagation delay time, high-to-low-level output] I _O ≈ 200 mA,	CL = 15 pF,		18	25	50
t _{TLH}			$R_{L} = 50 \Omega$,	See Figure 1		5	8	ns
t _{THL}	Transition time, high-to-low-level output]			7	12	
Vall	High lovel output voltage offer switching	SN55453B	V _S = 20 V,	I _O ≈ 300 mA,		V _S -6.5		mV
VOH	High-level output voltage after switching	SN75453B	See Figure 2		V _S -6.5			ΠV



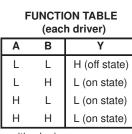
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logic symbol[†]

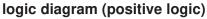


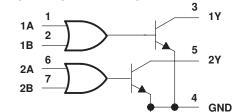
[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

Pin numbers shown are for the D, JG, and P packages.



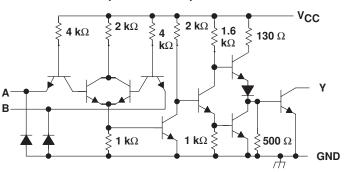
positive logic: $Y = \overline{A+B} \text{ or } \overline{AB}$





ф

schematic (each driver)



Resistor values shown are nominal.

electrical characteristics over recommended operating free-air temperature range

	PARAMETER	TEST CON	DITIONOT	S	N55454E	3	S	N75454E	3	UNIT
	PARAMEIER	TEST CONDITIONS [‡]		MIN	TYP§	MAX	MIN	ΤΥΡ§	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	lı = -12 mA		-1.2	-1.5		-1.2	-1.5	V
Vei		$V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$	VIH = MIN,		0.25	0.5		0.25	0.4	V
VOL	VOL Low-level output voltage	V _{CC} = MIN, I _{OL} = 300 mA	VIH = MIN,		0.5	0.8		0.5	0.7	v
ЮН	High-level output current	V _{CC} = MIN, V _{OH} = 30 V	VIL = 0.8 V,			300			100	μA
Ц	Input current at maximum input voltage	$V_{CC} = MAX,$	Vj = 5.5 V			1			1	mA
ΙIΗ	High-level input current	$V_{CC} = MAX,$	V _I = 2.4 V			40			40	μA
۱ _{IL}	Low-level input current	$V_{CC} = MAX,$	V _I = 0.4 V		-1	-1.6		-1	-1.6	mA
ICCH	Supply current, outputs high	$V_{CC} = MAX,$	V _I = 0		13	17		13	17	mA
ICCL	Supply current, outputs low	$V_{CC} = MAX,$	V _I = 5 V		61	79		61	79	mA

[‡] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

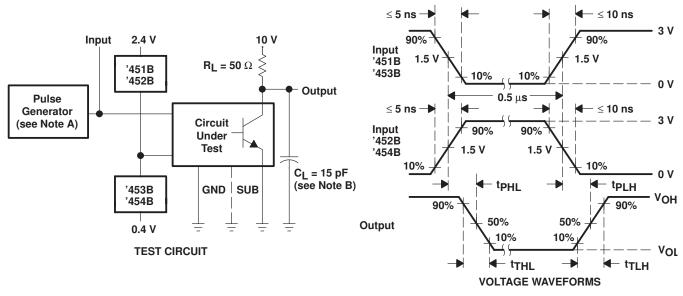
§ All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

	PARAMETER		TEST CO	NDITIONS	MIN	ТҮР	MAX	UNIT
^t PLH	Propagation delay time, low-to-high-level output				27	35		
^t PHL	Propagation delay time, high-to-low-level output	I _O ≈ 200 mA,	CL = 15 pF,		24	35		
t _{TLH}	Transition time, low-to-high-level output	R _L = 50 Ω,	See Figure 1		5	8	ns	
t _{THL}	Transition time, high-to-low-level output				7	12		
Val	High-level output voltage after switching	SN55454B	V _S = 20 V,	I _O ≈ 300 mA,		V _S -6.5		mV
VOH	righter switching	SN75454B	See Figure 2		V _S -6.5			шv



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. The pulse generator has the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω . B. C_L includes probe and jig capacitance.

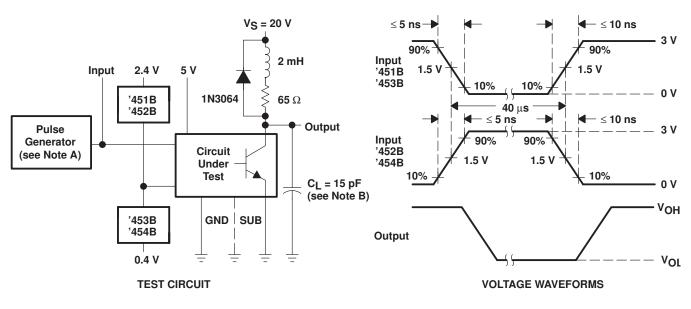


Figure 1. Test Circuit and Voltage Waveforms, Complete Drivers

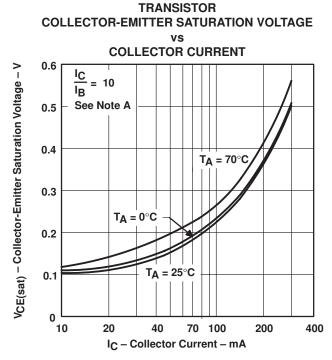
NOTES: A. The pulse generator has the following characteristics: PRR \leq 12.5 kHz, Z_O = 50 $\Omega.$ B. CL includes probe and jig capacitance.

Figure 2. Test Circuit and Voltage Waveforms for Latch-Up Test of Complete Drivers



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NOTE A: These parameters must be measured using pulse techniques, $t_{\text{W}}=300~\mu\text{s},$ duty cycle $\leq 2\%.$

Figure 3





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PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
5962-9563301Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9563301Q2A SNJ55 453BFK	Samples
5962-9563301QPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9563301QPA SNJ55453B	Samples
77049012A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	77049012A SNJ55 452BFK	Samples
7704901PA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	7704901PA SNJ55452B	Samples
77049022A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	77049022A SNJ55 451BFK	Samples
7704902PA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	7704902PA SNJ55451B	Samples
JM38510/12902BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510 /12902BPA	Samples
JM38510/12903BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510 /12903BPA	Samples
JM38510/12905BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510 /12905BPA	Samples
M38510/12902BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510 /12902BPA	Samples
M38510/12903BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510 /12903BPA	Samples
M38510/12905BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510 /12905BPA	Samples
SN55451BJG	ACTIVE	CDIP	JG	8	50	TBD	A42	N / A for Pkg Type	-55 to 125	SN55451BJG	Samples
SN55452BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	SN55452BJG	Samples
SN55453BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	SN55453BJG	Samples
SN55454BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	SN55454BJG	Samples



PACKAGE OPTION ADDENDUM

10-Jun-2014

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sample
SN75451BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75451B	Sample
SN75451BDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75451B	Sample
SN75451BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75451B	Sample
SN75451BDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75451B	Sample
SN75451BDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75451B	Sample
SN75451BP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75451BP	Sample
SN75451BPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75451BP	Sample
SN75451BPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	A451B	Sample
SN75452BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75452B	Sample
SN75452BDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75452B	Sample
SN75452BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75452B	Sample
SN75452BDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75452B	Sample
SN75452BDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75452B	Sample
SN75452BP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75452BP	Sample
SN75452BPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75452BP	Sample
SN75452BPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	A452B	Sample
SN75452BPSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	A452B	Sample
SN75452BPSRG4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	A452B	Sample



PACKAGE OPTION ADDENDUM

10-Jun-2014

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Sample
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN75453BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75453B	Sample
SN75453BDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75453B	Sample
SN75453BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75453B	Sample
SN75453BDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75453B	Sampl
SN75453BP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75453BP	Sampl
SN75453BPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75453BP	Sampl
SN75453BPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	A453B	Sampl
SN75454BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75454B	Sampl
SN75454BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75454B	Sampl
SN75454BP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75454BP	Sampl
SN75454BPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75454BP	Sampl
SN75454BPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	A454B	Sampl
SNJ55451BFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	77049022A SNJ55 451BFK	Sampl
SNJ55451BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	7704902PA SNJ55451B	Samp
SNJ55452BFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	77049012A SNJ55 452BFK	Samp
SNJ55452BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	7704901PA SNJ55452B	Samp
SNJ55453BFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9563301Q2A SNJ55	Sampl



10-Jun-2014

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
										453BFK	
SNJ55453BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9563301QPA SNJ55453B	Samples
SNJ55454BFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	SNJ55 454BFK	Samples
SNJ55454BJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	SNJ55 454BJG	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Jun-2014

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OTHER QUALIFIED VERSIONS OF SN55451B, SN55452B, SN55453B, SN55454B, SN75451B, SN75452B, SN75453B, SN75454B :

• Catalog: SN75451B, SN75452B, SN75453B, SN75454B

• Military: SN55451B, SN55452B, SN55453B, SN55454B

- NOTE: Qualified Version Definitions:
 - Catalog TI's standard catalog product
 - Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com

TAPE AND REEL INFORMATION

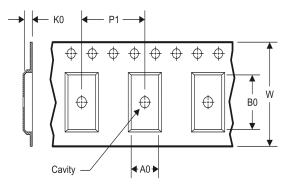
REEL DIMENSIONS

TEXAS INSTRUMENTS





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

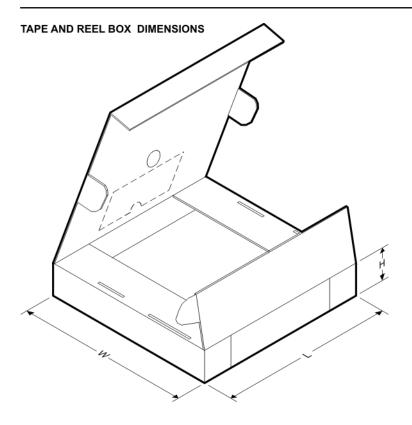
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75451BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75451BPSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN75452BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75452BPSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN75453BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75453BPSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN75454BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75454BPSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1

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PACKAGE MATERIALS INFORMATION

14-Jul-2012



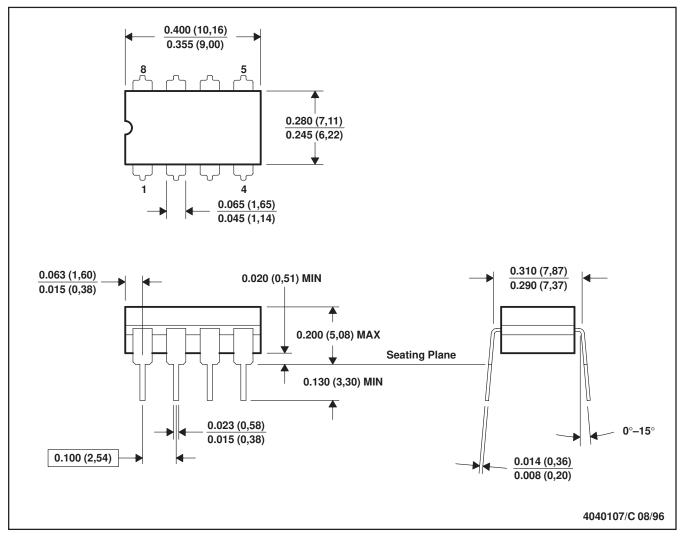
*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75451BDR	SOIC	D	8	2500	340.5	338.1	20.6
SN75451BPSR	SO	PS	8	2000	367.0	367.0	38.0
SN75452BDR	SOIC	D	8	2500	340.5	338.1	20.6
SN75452BPSR	SO	PS	8	2000	367.0	367.0	38.0
SN75453BDR	SOIC	D	8	2500	340.5	338.1	20.6
SN75453BPSR	SO	PS	8	2000	367.0	367.0	38.0
SN75454BDR	SOIC	D	8	2500	340.5	338.1	20.6
SN75454BPSR	SO	PS	8	2000	367.0	367.0	38.0

MECHANICAL DATA

MCER001A - JANUARY 1995 - REVISED JANUARY 1997



CERAMIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8



LEADLESS CERAMIC CHIP CARRIER

FK (S-CQCC-N**) 28 TERMINAL SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE

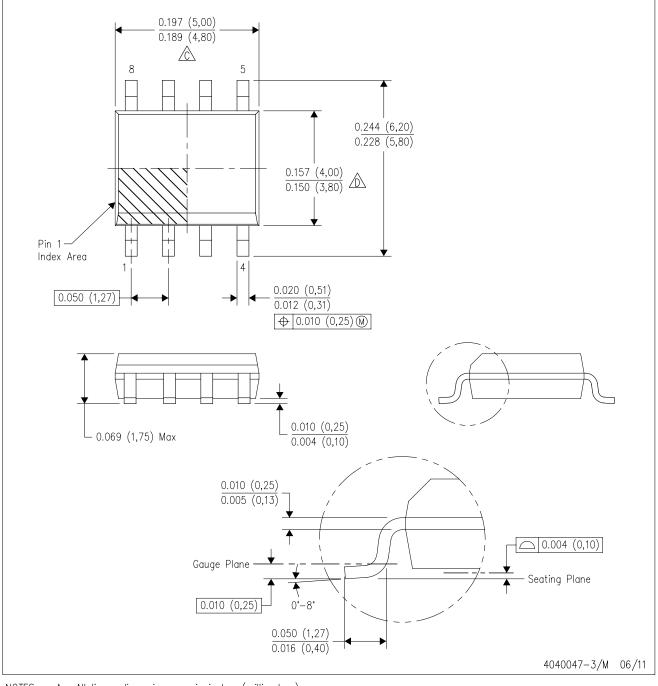


- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

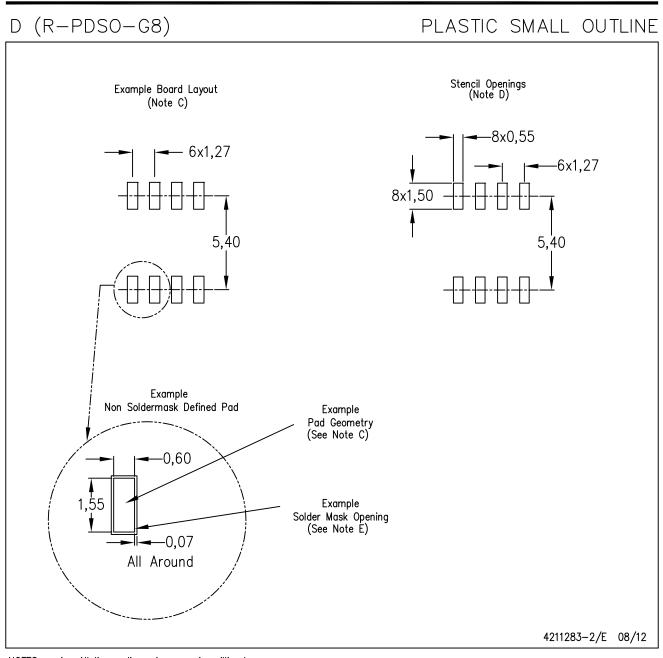
PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

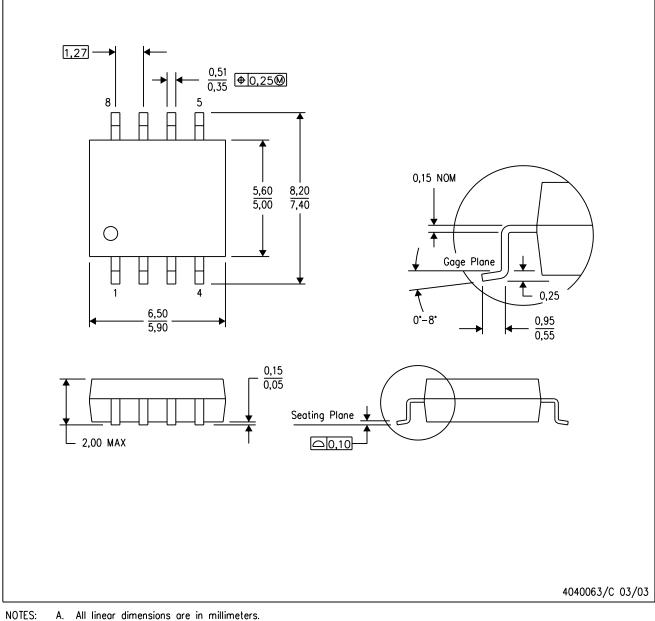
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

PS (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

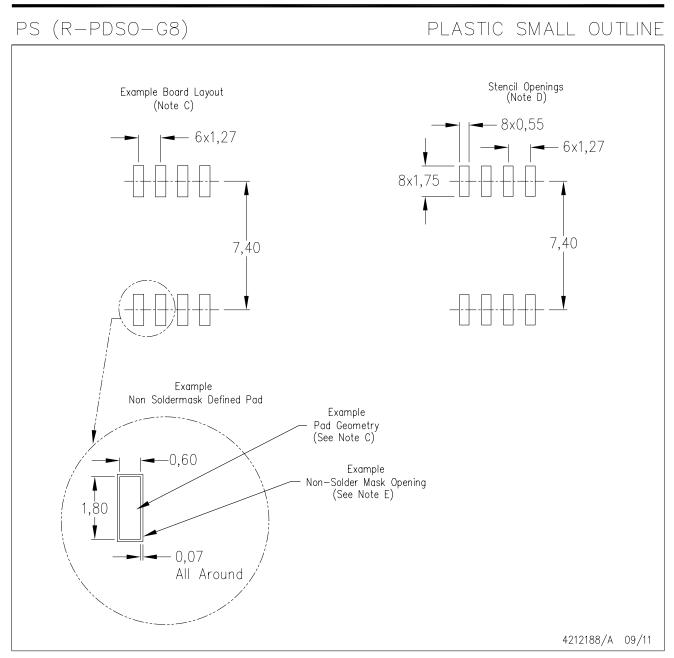


A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.





NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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